

SANYO Semiconductors **DATA SHEET**

STK433-060-E — 2-channel class AB audio power IC, 50W+50W

Overview

The STK433-060-E is a hybrid IC designed to be used in 50W × 2ch class AB audio power amplifiers.

Applications

Audio power amplifiers.

Features

- Pin-to-pin compatible outputs ranging from 30W to 60W.
- Can be used to replace the STK433-100 series (80W to 150W/2ch)and STK433-200/-300 series (3-channel) due to its pin compatibility
- Miniature package (47.0mm \times 25.6mm \times 9.0mm)
- Output load impedance: $R_{\rm L} = 6\Omega$ to 4Ω supported
- Allowable load shorted time: 0.3 second
- Allows the use of predesigned applications for standby and mute circuits.

Series Models

	STK433-030-E	STK433-040-E	STK433-060-E	STK433-070-E							
Output 1 (10%/1kHz)	30W×2 channels	40W×2 channels	50W×2 channels	60W×2 channels							
Output 2 (0.4%/20Hz to 20kHz)	20W×2 channels	25W×2 channels	35W×2 channels	40W×2 channels							
Max. rated V _{CC} (quiescent)	±34V	±38V	±46V	±50V							
Max. rated V _{CC} (6Ω)	±32V	±36V	±40V	±44V							
Max. rated V _{CC} (4Ω)	±26V	±30V	±33V	±37V							
Recommended operating V_{CC} (6 Ω)	±21V	±24V	±27V	±29V							
Dimensions (excluding pin height)		47.0mm×25.6mm×9.0mm									

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Specifications

Absolute Maximum Ratings at Ta = 25°C (excluding rated temperature items), Tc=25°C unless otherwise specified

Parameter	Symbol	Symbol Conditions		Unit
Maximum quiescent supply voltage 0	V _{CC} max (0)	When no signal	±46	V
Maximum supply voltage 1	V _{CC} max (1)	R _L ≥6Ω	±40	V
Maximum supply voltage 2	V _{CC} max (2)	$R_L=4\Omega$	±33	V
Minimum operating supply voltage	V _{CC} min		±10	V
Pin 13 input voltage	VST max		-0.3 to +5.5	V
Thermal resistance	θј-с	Per power transistor	3.5	°C/W
Junction temperature	Tj max	Both the Tj max and Tc max conditions must be met.	150	°C
IC substrate operating temperature	Tc max		125	°C
Storage temperature	Tstg		-30 to +125	°C
Allowable load shorted time *4	ts	V_{CC} =±27V, R _L =6 Ω , f=50Hz, P _O =35W, 1-channel active	0.3	s

Operating Characteristics at Tc=25°C, R_L =6 Ω , R_g =600 Ω , VG=30dB, non-inductive load R_L , unless otherwise specified

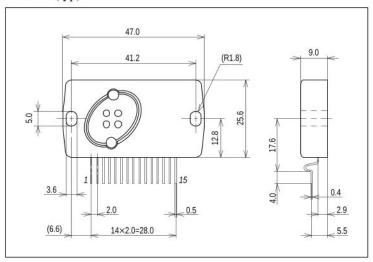
					Condition						
Parameter	Symbol		V _{CC} (V)	f (Hz)	Po (W)	THD (%)		min	typ	max	unit
Output power	*1	P _O (1)	±27	20 to 20k		0.4		33	35		
		P _O (2)	±27	1k		10			50		w
		P _O (3)	±22	1k		1	R _L =4Ω		35		
Total harmonic distortion *1	*1	THD (1)	±27	20 to 20k						0.4	%
		THD (2)	±27	1k	5.0]		0.02		9/0
Frequency characteristics	*1	f _L , f _H	±27		1.0		+0 -3dB		20 to 50k		Hz
Input impedance		ri	±27	1k	1.0				55		kΩ
Output noise voltage	*3	V _{NO}	±33				Rg=2.2kΩ			1.0	mVrms
Quiescent current		Icco	±33				No loading	20	45	70	mA
Standby current		^I CST	±33							1	mA
Output neutral voltage		VN	±33					-70	0	+70	mV
Pin 13 voltage when stand	by	VST ON	±27				Standby			0.6	V
Pin 13 voltage when stand	by	VST OFF	±27				Operating	2.5			V

[Remarks]

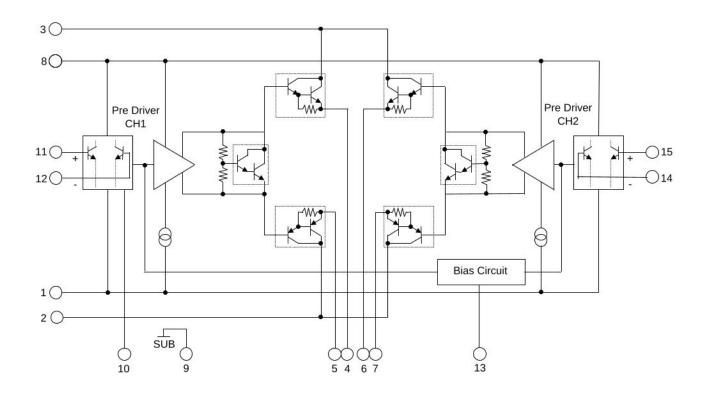
- *1: For 1-channel operation
- *2: Unless otherwise specified, use a constant-voltage power supply to supply power when inspections are carried out.
- *3: The output noise voltage values shown are peak values read with a VTVM. However, an AC stabilized (50Hz) power supply should be used to minimize the influence of AC primary side flicker noise on the reading.
- *4: Use the transformer power supply circuit shown in the figure below for allowable load shorted time measurement.
- *5: Please connect -preV_{CC} Pin (#1 pin) with the stable minimum voltage and connect so that current does not flow in by reverse bias.
- * Thermal design must be implemented based on the conditions under which the customer's end products are expected to operate on the market.
- * A thermoplastic adhesive is used to adhere the case.

Package Dimensions

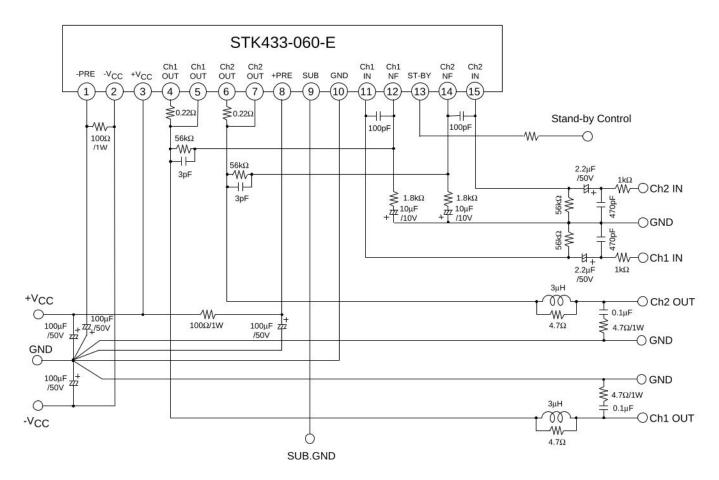
unit:mm (typ)



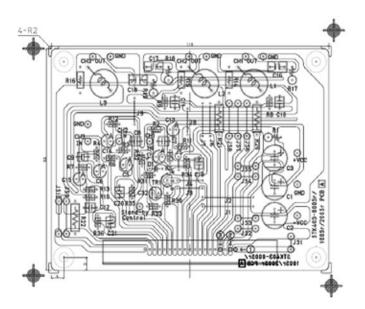
Internal Equivalent Circuit



Application Circuit Example



Sample PCB Trace Pattern



STK433-000/-200/STK403-100Sr PCB PARTS LIST

PCB Name: STK403-000Sr/100Sr/200Sr PCBA

				Comp	onent				
Location No. (*3)		PARTS	STK433-030/-040	STK433-060/-070					
Location No. (*	3)	PARTS	RATING	STK433-230/-240	STK433-260/-270				
				STK403-090 to130					
Hybrid IC#1 Pin Position		2		D					
R01		ERG1SJ101	100Ω, 1W	enable					
R02, R03 (R4)		RN16S102FK	1kΩ, 1/6W	enable					
R05, R06, R08, R09 (R7,	R10)	RN16S563FK	56kΩ, 1/6W	ena	ible				
R11, R12 (R13)		RN16S182FK	1.8kΩ, 1/6W	ena	ıble				
R14, R15 (R16)		RN14S4R7FK	4.7Ω, 1/4W	ena	ble				
R17, R18 (R19)		ERX1SJ4R7	4.7Ω, 1W	ena	ible				
R20, R21 (R22)		ERX2SJR22	0.22Ω, 2W	short	enable				
C01, C02, C03		100MV100HC	100μF, 100V	ena	ible				
C04, C05 (C06)		50MV2R2HC	2.2μF, 50V	enabl	e (*1)				
C07, C08 (C09)		DD104-63B471K50	470pF, 50V	ena	ıble				
C10, C11 (C12)		DD104-63CJ030C50	3pF, 50V	enabl	e (*2)				
C13, C14 (C15)		10MV10HC	10μF, 10V	enabl	e (*1)				
C16, C17 (C18)		ECQ-V1H104JZ	0.1μF, 50V	ena	ıble				
C19, C20 (C21)		DD104-63B***K50	***pF, 50V	100)pF				
R34, R35 (R36)		RN16S302FK	3kΩ, 1/6W	Short					
L01, L02 (L3)		-	3µН	ena	ble				
Stand-By Control Circuit	Tr1	2SC2274 (Reference)	VCE≥50V, IC≥10mA	enable					
	D1	GMB01 (Reference)	Di	ena	ble				
	R30	RN16S512FK	5.1kΩ, 1/6W	STK433-	STK433-*00series				
		RN16S103FK	13kΩ, 1/6W	STK403-	100series				
	R31	RN16S333FK	33kΩ, 1/6W	ena	ible				
	R32	RN16S102FK	1kΩ, 1/6W	ena	ible				
	R33	RN16S202FK	2kΩ, 1/6W	ena	ble				
	C32	10MV33HC	33μF, 10V	ena	ble				
J1, J2, J3, J4, J5, J6, J8, J	19	i i		ena	ible				
J7, JS2, JS3, JS4, JS5, JS	57 JS8, JS9		-		. 3				
JS6, JS10		2	¥	ena	ible				
JS1		5		ena	ble				

^(*1) Capacitor mark "A" side is "-" (negative).

^(*2) STK433-200Sr (3ch) is 8pF use.

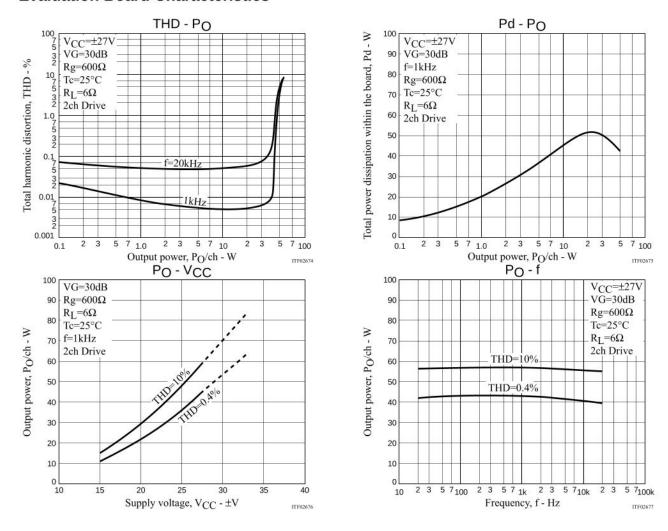
^(*3) Location No.() parts is STK433-200Sr (3ch) only use.

STK433-060-E

Pin Assignments [STK433-000/-100/-200Sr & STK415/416-100Sr Pin Layout]

STK433-000/-100/-200Sr	<u> </u>	41	3/4]	0-1	1	2	3 3	ayo 4	աւ <u>յ</u> 5	6	7		9	10	11	10	13	1.4	15			—	_
2-channel class-AB					1	2	3	4	30000		188	8	- 5	10	11	12	13	14	15				_
													AB/2	.uum		107007	- 251	220					_
STK433-030-E 30W/JEITA					12	-	+	0	0	0	0	+	100000	9500		N	S	N	I				
STK433-040-E 40W/JEITA					Р	٧	٧	U	U	U	U	Р	S	G	N	F	Т	F	N				
STK433-060-E 50W/JEITA					R	С	С	Т	Т	Т	Т	R	U	N	1	1	Α	1	1				
STK433-070-E 60W/JEITA					Е	С	С	1	1	1	1	E	В	D	С	С	N	С	С				
								С	С	С	С		•		Н	Н	D	Н	Н				
STK433-090-E 80W/JEITA								Н	Н	Н	Н		G		1	1	1	2	2				
STK433-100-E 100W/JEITA								1	1	2	2		N				В						
STK433-120-E 120W/JEITA								+	21	+	-		D				Υ						
STK433-130-E 150W/JEITA									,												_		
3-channel class-AB					1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
o chamer diaso Ab									3-	chan	nel c	lass	AB/2	.00m	ım								
STK433-230A-E 30W/JEITA					-		+	0	0	0	0	+			ĵ.	Ν	S	N	1	Ĩ	N	0	0
STK433-240A-E 40W/JEITA					Р	٧	٧	U	U	U	U	Р	S	G	Ν	F	Т	F	N	N	F	U	U
STK433-260A-E 50W/JEITA					R	С	С	Т	Т	Т	Т	R	U	N	1	1	Α	1	1	1	1	Т	Т
STK433-270-E 60W/JEITA					Ε	С	С	1	1	1	1	Е	В	D	С	С	N	С	С	С	С	1	1
STK433-290-E 80W/JEITA								С	С	С	С				Н	Н	D	Н	н	н	н	С	С
STK433-300-E 100W/JEITA								Н	н	Н	Н		G		1	1	1	2	2	3	3	Н	н
STK433-320-E 120W/JEITA								1	1	2	2		N				В					3	3
STK433-330-E 150W/JEITA								+	_	+	-		D				Υ					+	-
2	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19				
2-channel class-H									2	char	nnel	class	H/2.	00m	m								
STK415-090-E 80W/JEITA	+		+	2	-21	12.5	+	0	0	0	0	+			Ĩ	N	s	N	I				
STK415-100-E 90W/JEITA	V	V	0	0	Р	V	٧	U	U	U	U	Р	s	G	N	F	Т	F	N				
STK415-120-E 120W/JEITA	L	L	F	F	R	н	Н	Т	Т	Т	Т	R	υ	N	1	1	Α	1	1				
STK415-130-E 150W/JEITA			F	F	Е			1	1	1	1	E	В	D	С	С	N	С	С				
STK415-140-E 180W/JEITA			s	S				С	С	С	С				Н	Н	D	Н	н				
			Е	Е				н	н	н	н		G		1	1	1	2	2				
			Т	Т				1	1	2	2		N			20.000	В	55550					
			100					+	-	+	-		D				Y						
1.1. A71. W	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
3-channel class-H									3-	char	nnel	class	H/2.	00m	m								.53
STK416-090-E 80W/JEITA	+		+	2	-2	540	+	0	0	0	0	+			И	Ν	s	N	1	Ţ	N	0	0
STK416-100-E 90W/JEITA	V	V	0	0	Р	٧	٧	U	U	U	U	Р	s	G	N	F	Т	F	N	N	F	U	U
STK416-120-E 120W/JEITA	L	L	F	F	R	н	Н	Т	Т	Т	Т	R	υ	N	1	1	Α	1	1	1	1	Т	Т
STK416-130-E 150W/JEITA			F	F	Е			1	1	1	1	E	В	D	С	С	N	С	С	С	С	1	1
			S	S				С	С	С	С				Н	н	D	Н	н	н	н	С	С
			Е	Е				н	н	н	Н		G		1	1		2	2	3	3	Н	Н
			Т	Т				1	1	2	2		N				В					3	3
								+	21	+	-		D				Υ					+	-

Evaluation Board Characteristics



[Thermal Design Example for STK433-060-E ($R_L = 6\Omega$)]

The thermal resistance, θc -a, of the heat sink for total power dissipation, Pd, within the hybrid IC is determined as follows.

Condition 1: The hybrid IC substrate temperature, Tc, must not exceed 125°C.

$$Pd \times \theta c-a + Ta < 125^{\circ}C \qquad (1)$$

Ta: Guaranteed ambient temperature for the end product

Condition 2: The junction temperature, Tj, of each power transistor must not exceed 150°C.

$$Pd \times \theta c-a + Pd/N \times \theta j-c + Ta < 150$$
°C(2)

N: Number of power transistors

θj-c: Thermal resistance per power transistor

However, the power dissipation, Pd, for the power transistors shall be allocated equally among the number of power transistors.

The following inequalities result from solving equations (1) and (2) for θ c-a.

$$\theta c-a < (125 - Ta)/Pd$$
(1)'

When the following specifications have been stipulated, the required heat sink thermal resistance can be determined from formulas (1)' and (2)'.

Supply voltage
Load resistance
Guaranteed ambient temperature
Ta

[Example]

When the IC supply voltage, V_{CC} , is $\pm 27V$ and R_L is 6Ω , the total power dissipation, Pd, within the hybrid IC, will be a maximum of 52W at 1kHz for a continuous sine wave signal according to the Pd-PO characteristics. For the music signals normally handled by audio amplifiers, a value of 1/8PO max is generally used for Pd as an estimate of the power dissipation based on the type of continuous signal. (Note that the factor used may differ depending on the safety standard used.)

This is:

Pd
$$\approx 40W$$
 (when 1/8PO max. = 6.25W, PO max. = 50W).

The number of power transistors in audio amplifier block of these hybrid ICs, N, is 4, and the thermal resistance per transistor, θ j-c, is 3.5°C/W. Therefore, the required heat sink thermal resistance for a guranteed ambient temperature, Ta, of 50°C will be as follows.

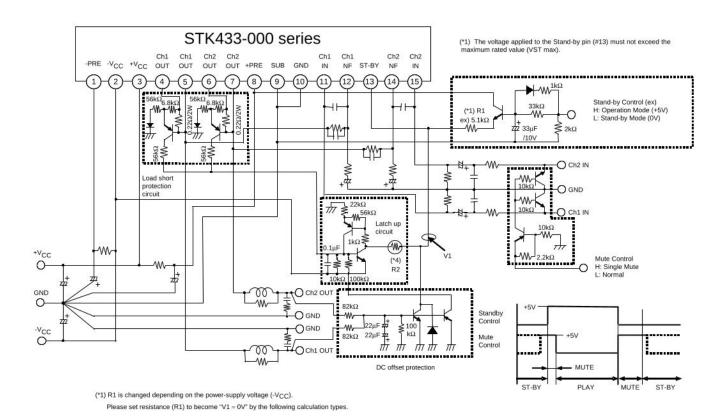
From formula (1)'
$$\theta c\text{-a} < (125 - 50)/40$$

 < 1.87
From formula (2)' $\theta c\text{-a} < (150 - 50)/40 - 3.5/4$
 < 1.62

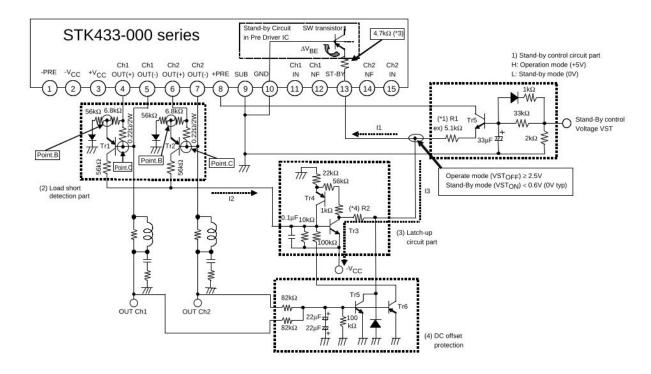
Therefore, the value of 1.62°C/W, which satisfies both of these formulae, is the required thermal resistance of the heat sink.

Note that this thermal design example assumes the use of a constant-voltage power supply, and is therefore not a verified design for any particular user's end product.

STK433-000 Series Standby Control, Mute Control, Load-short Protection & DC offset Protection application



STK433-000 Series Application Explanation



The protection circuit application for the STK433-000sr consists of the following blocks (blocks (1) to (4)).

- (1) Standby control circuit block
- (2) Load short-circuit detection block
- (3) Latch-up circuit block
- (4) DC voltage protection block

1) Standby control circuit block

Concerning pin 13 reference voltage VST

<1> Operation mode

The switching transistor of the predriver IC turns on when the pin 13 reference voltage, VST, becomes greater than or equal to 2.5V, placing the amplifier into the operation mode.

Example: When VST (min.) = 2.5V

I1 is approximately equal to 0.40mA since VST = (*2) × IST + 0.6V \rightarrow 2.5V = 4.7k Ω × IST + 0.6V.

<2> Standby mode

The switching transistor of the predriver IC turns off when the pin 13 reference voltage, VST, becomes lower than or equal to 0.6V (typ. 0V), placing the amplifier into the standby mode.

Example: When VST = 0.6V

I1 is approximately equal to 0mA since VST = (*2) × IST + 0.6V \rightarrow 0.6V = 4.7k Ω × IST + 0.6V.

(*1) Limiting resistor

Determine the value of R1 so that the voltage VST applied to the standby pin (pin 13) falls within the rating (+2.5V to 5.5V (typ. 3.0V)).

- (*2) The standby control voltage must be supplied from the host including microcontrollers.
- (*3) A $4.7k\Omega$ limiting resistor is also incorporated inside the hybrid IC (at pin 13).

2) Load short-circuit detection block

Since the voltage between point B and point C is less than 0.6V in normal operation mode ($V_{BE} < 0.6V$) and TR1 (or TR2) is not activated, the load short-circuit detection block does not operate.

When a load short-circuit occurs, however, the voltage between point B and point C becomes larger than 0.6V, causing TR1 (or TR2) to turn on $(V_{BE} > 0.6V)$, and current I2 to flows.

3) Latch-up circuit block

TR3 is activated when I2 is supplied to the latch-up circuit.

When TR3 turns on and current I3 starts flowing, VST goes down to 0V (standby mode), protecting the power amplifier.

Since TR3 and TR4 configure a thyristor, once TR3 is activated, the IC is held in the standby mode.

To release the standby mode and reactivate the power amplifier, it is necessary to set the standby control voltage (*2) temporarily low (0V). Subsequently, when the standby control is returned to high, the power amplifier will become active again.

(*4) The I3 value varies depending on the supply voltage. Determine the value of R2 using the formula below, so that I1 is equal to or less than I3.

$$I1 \le I3 = V_{CC}/R2$$

4) DC offset protection block

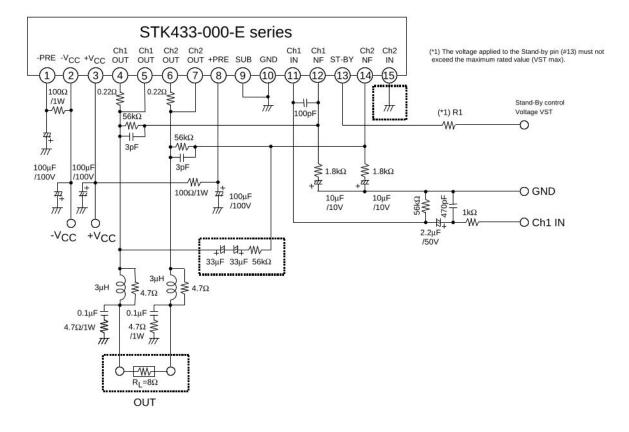
The DC offset protection circuit is activated when ± 0.5 V (typ) voltage is applied to either "OUT CH1" or "OUT CH2," and the hybrid IC is shut down (standby mode).

To release the IC from the standby mode and reactivate the power amplifier, it is necessary to set the standby control voltage temporarily low (0V).

Subsequently, when the standby control is returned to high (+5V, for example), the power amplifier will become active again.

The protection level must be set using the $82k\Omega$ resistor. Furthermore, the time constant must be determined using $22\mu/22\mu$ capacitors to prevent the amplifier from malfunctioning due to the audio signal.

STK433-000 Series BTL Application



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